

## 1. General description

Ultrafast power diode (Bare die without sawn).

## 2. Features and benefits

- Fast switching and soft reverse recovery characteristics
- Low forward voltage drop
- Low leakage current
- Low reverse recovery current
- Reduces switching losses in associated MOSFET or IGBT
- High operating temperature capability ( $T_{j(max)} = 175^{\circ}\text{C}$ )
- Bare die

## 3. Quick reference data

Table 1. Quick reference data

| Symbol                         | Parameter                       | Conditions  | Notes | Values |      |      | Unit |
|--------------------------------|---------------------------------|---|-------|--------|------|------|------|
| $V_{RRM}$                      | repetitive peak reverse voltage |   | [1]   | 600    |      |      | V    |
| $I_{F(AV)}$                    | average forward current         | $\delta = 0.5$ ; square-wave pulse  | [2]   | 60     |      |      | A    |
| Symbol                         | Parameter                       | Conditions  | Notes | Min    | Typ  | Max  | Unit |
| <b>Static characteristics</b>  |                                 |   |       |        |      |      |      |
| $V_F$                          | forward voltage                 | $I_F = 60\text{ A}$ ; $T_j = 25^{\circ}\text{C}$  | [2]   | -      | 1.55 | 2.00 | V    |
| <b>Dynamic characteristics</b> |                                 |   |       |        |      |      |      |
| $t_{rr}$                       | reverse recovery time           | $I_F = 1\text{ A}$ ; $V_R = 30\text{ V}$ ; $di_F/dt = 50\text{ A}/\mu\text{s}$ ; $T_j = 25^{\circ}\text{C}$ | [2]   | -      | -    | 55   | ns   |

## 4. Ordering information

Table 2. Ordering information

| Product type | Orderable part number | Description       | Packing method               |
|--------------|-----------------------|-------------------|------------------------------|
| WB60FV60AL   | WB60FV60ALZ           | Bare die on wafer | Unsawn wafer, Vacuum packing |

## 5. Limiting values

**Table 3. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol      | Parameter                           | Conditions  | Notes | Values     | Unit             |
|-------------|-------------------------------------|---|-------|------------|------------------|
| $V_{RRM}$   | repetitive peak reverse voltage     |   | [1]   | 600        | V                |
| $V_{RWM}$   | crest working reverse voltage       |   | [1]   | 600        | V                |
| $V_R$       | reverse voltage                     | DC  | [1]   | 600        | V                |
| $I_{F(AV)}$ | average forward current             | $\delta = 0.5$ ; square-wave pulse  | [2]   | 60         | A                |
| $I_{FRM}$   | repetitive peak forward current     | $\delta = 0.5$ ; $t_p = 25 \mu\text{s}$ ; square-wave pulse                                 | [2]   | 120        | A                |
| $I_{FSM}$   | non-repetitive peak forward current | $t_p = 10 \text{ ms}$ ; $T_{j(\text{init})} = 25 \text{ }^\circ\text{C}$ ; sine-wave pulse  | [2]   | 600        | A                |
|             |                                     | $t_p = 8.3 \text{ ms}$ ; $T_{j(\text{init})} = 25 \text{ }^\circ\text{C}$ ; sine-wave pulse | [2]   | 660        | A                |
| $T_j$       | junction temperature                |   |       | -40 to 175 | $^\circ\text{C}$ |

## 6. Characteristics

Table 4. Characteristics

| Symbol                         | Parameter             | Conditions  | Notes | Min | Typ  | Max  | Unit          |
|--------------------------------|-----------------------|---|-------|-----|------|------|---------------|
| <b>Static characteristics</b>  |                       |   |       |     |      |      |               |
| $V_F$                          | forward voltage       | $I_F = 60 \text{ A}; T_j = 25 \text{ }^\circ\text{C}$   | [2]   | -   | 1.55 | 2.00 | V             |
|                                |                       | $I_F = 60 \text{ A}; T_j = 150 \text{ }^\circ\text{C}$  | [2]   | -   | 1.20 | 1.60 | V             |
| $I_R$                          | reverse current       | $V_R = 600 \text{ V}; T_j = 25 \text{ }^\circ\text{C}$  | [1]   | -   | -    | 10   | $\mu\text{A}$ |
|                                |                       | $V_R = 600 \text{ V}; T_j = 125 \text{ }^\circ\text{C}$   | [2]   | -   | -    | 500  | $\mu\text{A}$ |
| <b>Dynamic characteristics</b> |                       |   |       |     |      |      |               |
| $t_{rr}$                       | reverse recovery time | $I_F = 1 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 50 \text{ A}/\mu\text{s}; T_j = 25 \text{ }^\circ\text{C}$    | [2]   | -   | -    | 55   | ns            |
|                                |                       | $I_F = 60 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 200 \text{ A}/\mu\text{s}; T_j = 25 \text{ }^\circ\text{C}$ | [2]   | -   | 53   | -    | ns            |

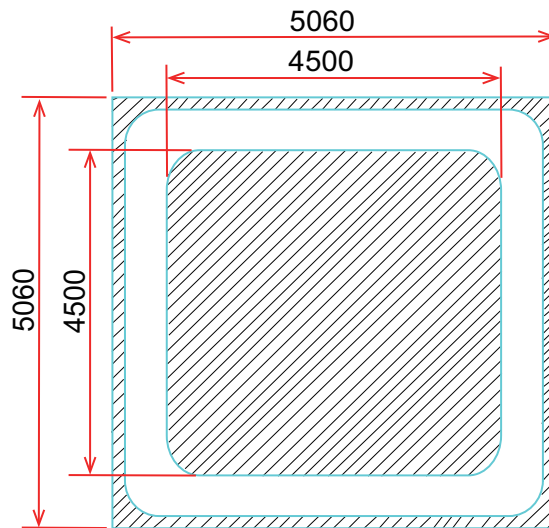
Notes:

[1] means that parameter are 100% test at  $T_{amb} = 25^\circ\text{C}$ .

[2] means that the guaranteed ratings and parameter limits will depend on the assembled structure. When correctly assembled with suitable die bonding and wire bonding, the device will have ratings and characteristics guaranteed in this data sheet, similar to the assembled device.

| MECHANICAL SPECIFICATIONS    |              |                 |
|------------------------------|--------------|-----------------|
| Chip size                    | 5.06 x 5.06  | mm <sup>2</sup> |
| Anode pad size               | 4.5 x 4.5    | mm <sup>2</sup> |
| Area total / active          | 25.6 / 20.25 | mm <sup>2</sup> |
| Thickness                    | 300          | µm              |
| Wafer size                   | 125          | mm              |
| Max possible chips per wafer | 418          | pcs             |
| Passivation                  | Glass        |                 |
| Front metal                  | Al           |                 |
| Back metal                   | Ti Ni Ag     |                 |

**CHIP LAYOUT**



**Die size: 5060µm x 5060µm**  
**Bond pad size: 4500µm x 4500µm**

## 7. Legal information

### Data sheet status

| Document status [1][2]         | Product status [3] | Definition  |
|--------------------------------|--------------------|---|
| Objective [short] data sheet   | Development        | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification      | This document contains data from the preliminary specification.                       |
| Product [short] data sheet     | Production         | This document contains the product specification.                                     |

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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## 8. Contents

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|                                |   |
|--------------------------------|---|
| 1. General description.....    | 1 |
| 2. Features and benefits ..... | 1 |
| 3. Quick reference data .....  | 1 |
| 4. Ordering information.....   | 1 |
| 5. Limiting values .....       | 2 |
| 6. Characteristics.....        | 3 |
| 7. Legal information .....     | 5 |
| 8. Contents .....              | 7 |

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